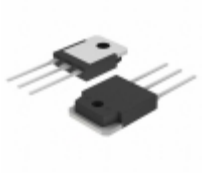



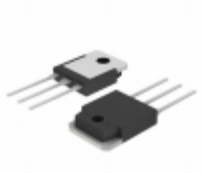
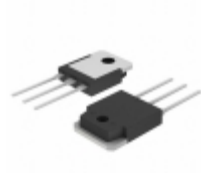

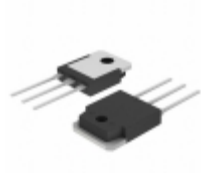
	<h2 style="color: red;">FQA38N30</h2>
	<p>Hersteller-Teilenummer: FQA38N30</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 300V 38.4A TO-3P</p> <hr/> <p>Datenblätter:  FQA38N30.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 22035 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA38N30
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 300V 38.4A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	22035 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3PN
Verlustleistung (max)	290W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	300V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	38.4A (Tc)
Rds On (Max) @ Id, Vgs	85 mOhm @ 19.2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	120nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4400pF @ 25V
Verpackung	Tube



















































FQA38N30 ist neu im Original, Suche FQA38N30 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA38N30 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQA38N30: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA40N25 Fairchild/ON Semiconductor MOSFET N-CH 250V 40A TO-3P</p>	 <p>FQA36N15 Fairchild/ON Semiconductor FQA36N15 FAIRCHILD</p>	 <p>FQA36P15_F109 AMI Semiconductor / ON Semiconductor MOSFET P-CH 150V 36A TO-3P</p>	 <p>FQA40N30 Fairchild/ON Semiconductor FQA40N30 FAIRCHILD</p>
 <p>FQA36P15 AMI Semiconductor / ON Semiconductor MOSFET P-CH 150V 36A TO-3P</p>	 <p>FQA36P15_F109 Fairchild/ON Semiconductor MOSFET P-CH 150V 36A TO-3P</p>	 <p>FQA40N50 Fairchild/ON Semiconductor FQA40N50 FAIRCHILD</p>	 <p>FQA36P15 Fairchild/ON Semiconductor MOSFET P-CH 150V 36A TO-3P</p>

heiße Teile

Mehr

 FQA28N50	 FQA28N50	 FQA28N50F	 FQA28N50F	 FQA30N40
 FQA30N40	 FQA32N20C	 FQA32N20C	 FQA33N10	 FQA33N10
 FQA33N10L	 FQA33N10L	 FQA34N20	 FQA34N20	 FQA34N20L
 FQA34N20L	 FQA34N25	 FQA34N25	 FQA35N40	 FQA35N40
 FQA36P15	 FQA36P15	 FQA36P15_F109	 FQA36P15_F109	 FQA38N30
 FQA40N25	 FQA40N25	 FQA40N30	 FQA40N50	 FQA40N50L
 FQA44N10	 FQA44N10	 FQA44N30	 FQA44N30	 FQA46N15
 FQA46N15	 FQA46N15_F109	 FQA46N15_F109	 FQA46P06	 FQA46P15
 FQA47P06	 FQA47P06	 FQA48N20	 FQA48N20	 FQA55N10
 FQA55N10	 FQA55N25	 FQA55N25	 FQA62N25C	 FQA62N25C

Contact us: Info@Y-IC.com

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